

ST1803DHI

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

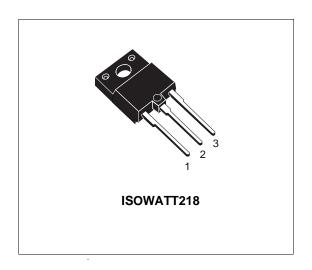
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- INTEGRATED FREE WHEELING DIODE
- HIGH VOLTAGE CAPABILITY (> 1500 V)
- HIGH SWITCHING SPEED
- TIGTHER hfe CONTROL
- IMPROVED RUGGEDNESS

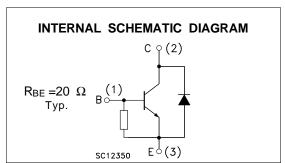
APPLICATIONS:

 HORIZONTAL DEFLECTION FOR COLOR TVS

DESCRIPTION

The ST1803DHI is manufactured using Diffused Collector technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	1500	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	600	V
V _В	Emitter-Base Voltage (Ic = 0)	7	V
Ic	Collector Current	10	Α
I _{CM}	Collector Peak Current (t _p < 5 ms)	15	Α
I_B	Base Current	4	Α
P _{tot}	Total Dissipation at T _c = 25 °C	50	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T _{stg}	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

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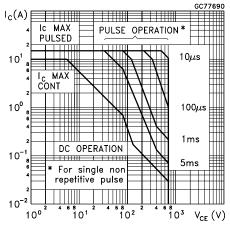
THERMAL DATA

ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

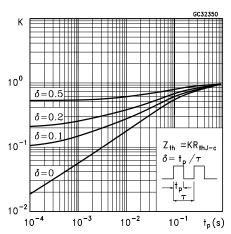
Symbol	Parameter	Test	Conditions	Min.	Тур.	Max.	Unit
ICES	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 1500 V V _{CE} = 1500 V	T _j = 125 °C			1 2	mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 4 V		130		400	mA
V _{(BR)EBO}	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = 700 mA		7			V
V _{CE(sat)*}	Collector-Emitter Saturation Voltage	I _C = 4 A I _C = 4 A	$I_B = 0.8 A$ $I_B = 1.2 A$		3	5 1.5	V V
V _{BE(sat)*}	Base-Emitter Saturation Voltage	I _C = 4 A	I _B = 0.8 A			1.2	V
h _{FE} *	DC Current Gain	I _C = 1 A I _C = 4.5 A I _C = 4.5 A	~ =	10 5	15 5	20 9	
V _F	Diode Forward Voltage	I _F = 5 A			1.5	2	V
t _s	INDUCTIVE LOAD Storage Time Fall Time	I _C = 4 A L _B = 5 μH f = 16 KHz	$I_{Bon(END)} = 0.8 A$ $V_{BB} = -2.5 V$ (see figure 1)		2.7 0.3	4 0.6	μs μs

^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

Safe Operating Area

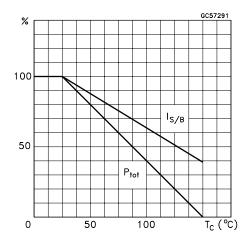


Thermal Impedance

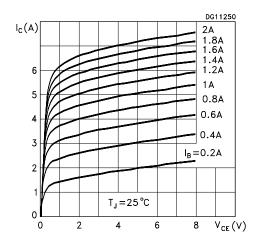


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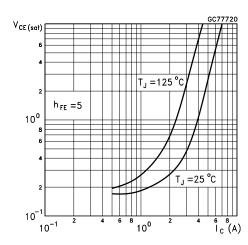
Derating Curve



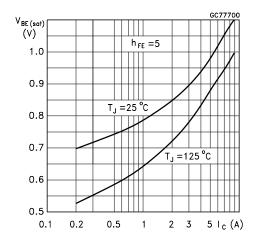
Output Characteristics



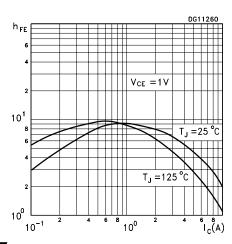
Collector Emitter Saturation Voltage



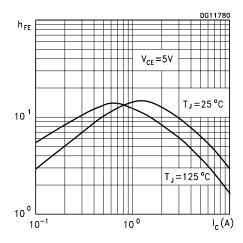
Base Emitter Saturation Voltage



DC Current Gain

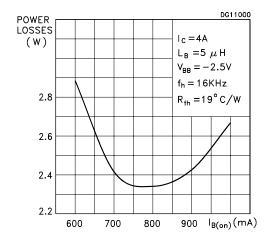


DC Current Gain

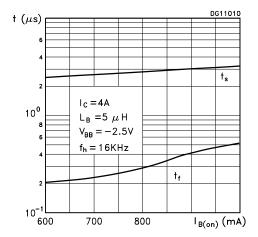


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Power Losses



Switching Time Inductive Load



Reverse Biased SOA

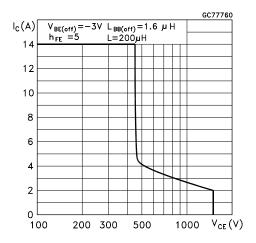
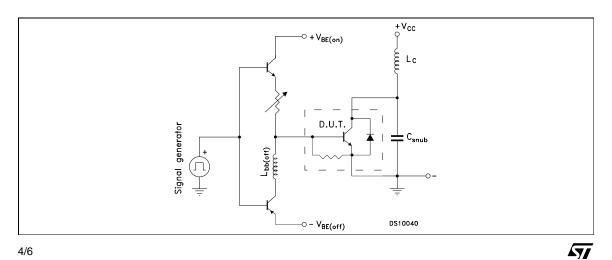
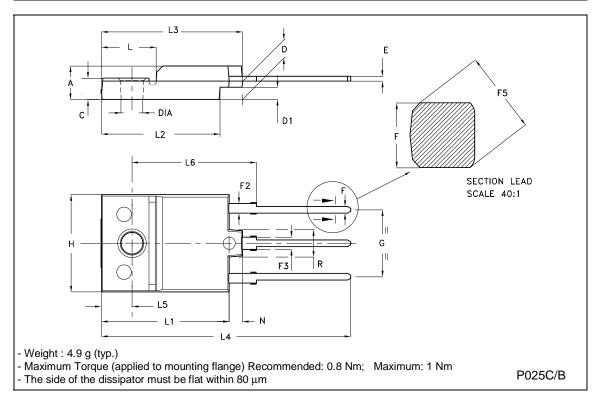


Figure 1: Inductive Load Switching Test Circuit.



ISOWATT218 NARROW LEADS MECHANICAL DATA

DIM.	mm			inch			
DINI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	5.35		5.65	0.211		0.222	
С	3.30		3.80	0.130		0.150	
D	2.90		3.10	0.114		0.122	
D1	1.88		2.08	0.074		0.082	
E	0.75		0.95	0.030		0.037	
F	0.75		0.95	0.030		0.037	
F2	1.50		1.70	0.059		0.067	
F3	1.90		2.10	0.075		0.083	
F5			1.10			0.043	
G	10.80		11.20	0.425		0.441	
Н	15.80		16.20	0.622		0.638	
L		9			0.354		
L1	20.80		21.20	0.819		0.835	
L2	19.10		19.90	0.752		0.783	
L3	22.80		23.60	0.898		0.929	
L4	40.50		42.50	1.594		1.673	
L5	4.85		5.25	0.191		0.207	
L6	20.25		20.75	0.797		0.817	
N	2.1		2.3	0.083		0.091	
R		4.6			0.181		
DIA	3.5		3.7	0.138		0.146	



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